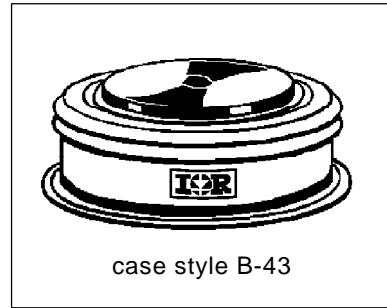


**FAST RECOVERY DIODES**
**Hockey Puk Version**
**Features**

- High power FAST recovery diode series
- 2.0 to 3.0  $\mu$ s recovery time
- High voltage ratings up to 2500V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Press-puk encapsulation
- Hockey Puk version case style B-43
- Maximum junction temperature 150°C

810A  
910A



case style B-43

**Typical Applications**

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

**Major Ratings and Characteristics**

Parameters	SD823C..C		Units
	S20	S30	
$I_{F(AV)}$	810	910	A
@ $T_{hs}$	55	55	°C
$I_{F(RMS)}$	1500	1690	A
$I_{FSM}$ @ 50Hz	9300	9600	A
@ 60Hz	9730	10050	A
$V_{RRM}$ range	1200 to 2500	1200 to 2500	V
$t_{rr}$	2.0	3.0	$\mu$ s
@ $T_J$	25	25	°C
$T_J$	- 40 to 150		°C

## SD823C..C Series

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

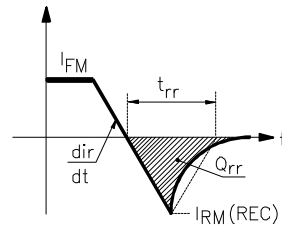
Type number	Voltage Code	$V_{RRM}$ , maximum repetitive peak reverse voltage V	$V_{RSM}$ , maximum non-repetitive peak rev. voltage V	$I_{RRM}$ max. @ $T_J = T_J$ max. mA
SD823C..C	12	1200	1300	50
	16	1600	1700	
	20	2000	2100	
	25	2500	2600	

#### Forward Conduction

Parameter	SD823C..C		Units	Conditions		
	S20	S30				
$I_{F(AV)}$ Max. average forward current @ heatsink temperature	810 (425) 55 (85)	910 (470) 55 (85)	A °C	180° conduction, half sine wave Double side (single side) cooled		
$I_{F(RMS)}$ Max. RMS forward current	1500	1690	A	@ 25°C heatsink temperature double side cooled		
$I_{FSM}$ Max. peak, one-cycle forward, non-repetitive surge current	9300	9600	A	t = 10ms No voltage		
	9730	10050		t = 8.3ms reapplied		
	7820	8070		t = 10ms 100% $V_{RRM}$		
	8190	8450		t = 8.3ms reapplied		
$I^2t$ Maximum $I^2t$ for fusing	432	460	KA <sup>2</sup> s	t = 10ms No voltage		
	395	420		t = 8.3ms reapplied		
	306	326		t = 10ms 100% $V_{RRM}$		
	279	297		t = 8.3ms reapplied		
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	4320	4600	KA <sup>2</sup> √s	t = 0.1 to 10ms, no voltage reapplied		
	$V_{F(TO)1}$ Low level value of threshold voltage	1.00		0.95	V	(16.7% x $\pi$ x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ max.
	$V_{F(TO)2}$ High level value of threshold voltage	1.11		1.06		( $I > \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ max.
	$r_{f1}$ Low level value of forward slope resistance	0.80		0.60	mΩ	(16.7% x $\pi$ x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ max.
$r_{f2}$ High level value of forward slope resistance		0.76	0.57	( $I > \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ max.		
$V_{FM}$ Max. forward voltage drop	2.20	1.85	V	$I_{pk} = 1500A$ , $T_J = T_J$ max, $t_p = 10ms$ sinusoidal wave		

#### Recovery Characteristics

Code	$T_J = 25^\circ\text{C}$ Typical $t_{rr}$ @ 25% $I_{RRM}$ (μs)	Test conditions			Max. values @ $T_J = 150^\circ\text{C}$		
		$I_{pk}$ Square Pulse (A)	di/dt (A/μs)	$V_r$ (V)	$t_{rr}$ @ 25% $I_{RRM}$ (μs)	$Q_{rr}$ (μC)	$I_{rr}$ (A)
S20	2.0	1000	50	-50	3.5	240	110
S30	3.0	1000	50	-50	5.0	380	130



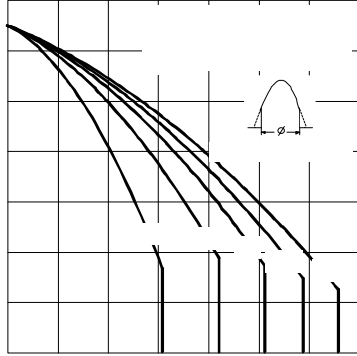


Fig. 3 - Current Ratings Characteristics

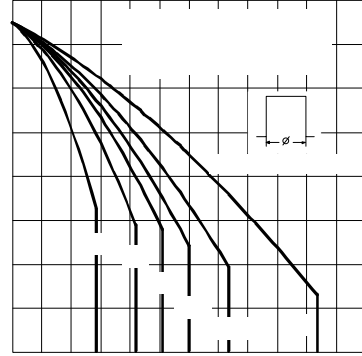


Fig. 4 - Current Ratings Characteristics

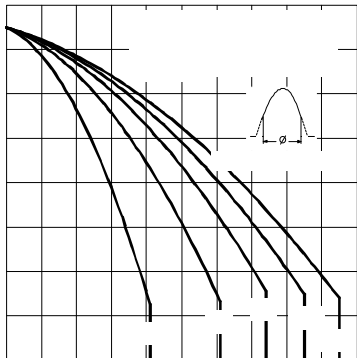


Fig. 5 - Current Ratings Characteristics

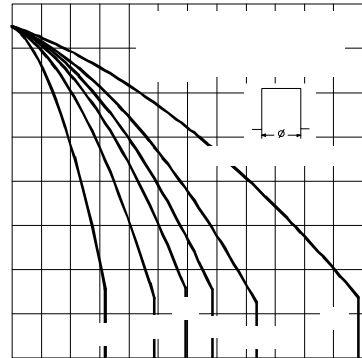


Fig. 6 - Current Ratings Characteristics

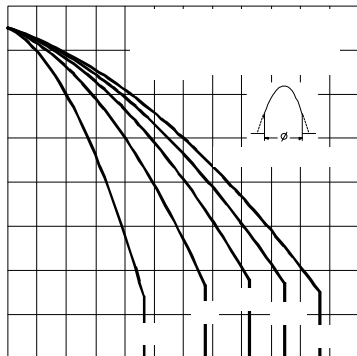


Fig. 7 - Current Ratings Characteristics

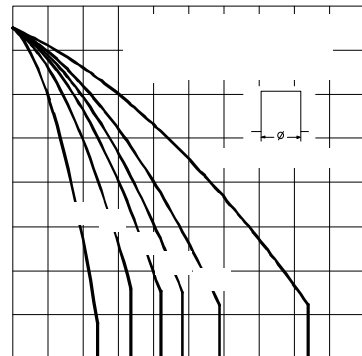


Fig. 8 - Current Ratings Characteristics

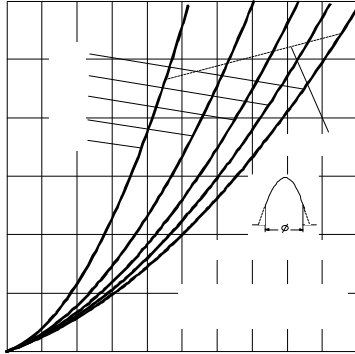


Fig. 9 - Forward Power Loss Characteristics

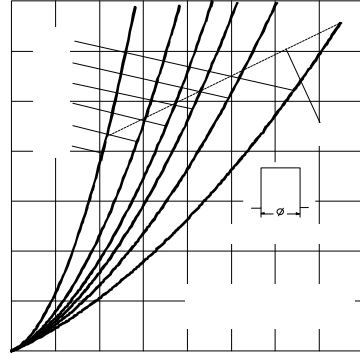


Fig. 10 - Forward Power Loss Characteristics

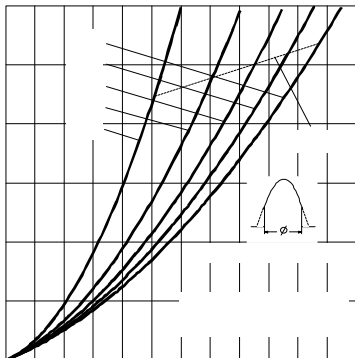


Fig. 11 - Forward Power Loss Characteristics

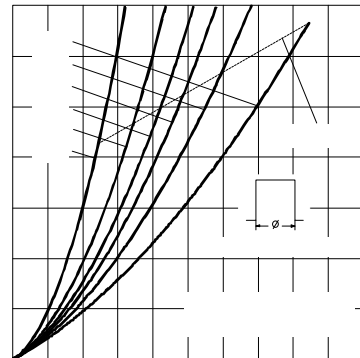


Fig. 12 - Forward Power Loss Characteristics

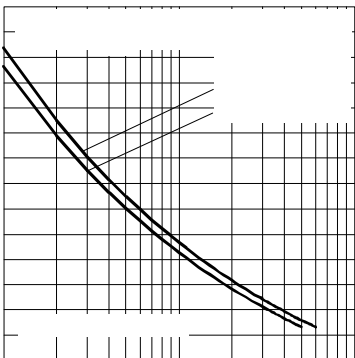


Fig. 13 - Maximum Non-repetitive Surge Current

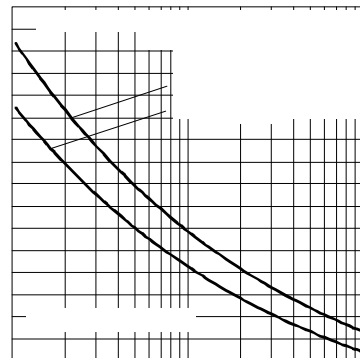


Fig. 14 - Maximum Non-repetitive Surge Current

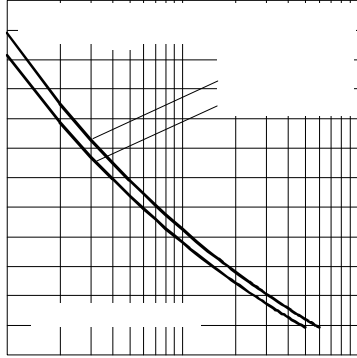


Fig. 15 - Maximum Non-repetitive Surge Current

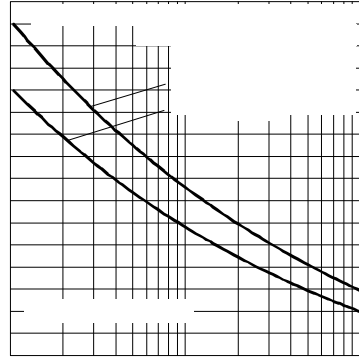


Fig. 16 - Maximum Non-repetitive Surge Current

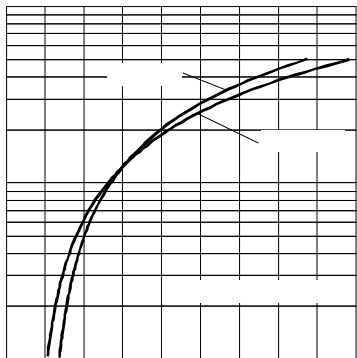


Fig. 17 - Forward Voltage Drop Characteristics

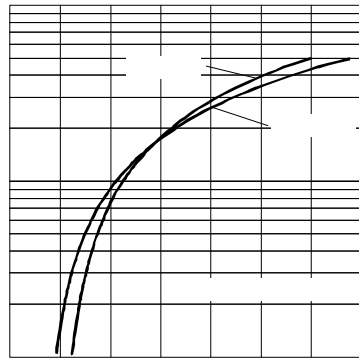


Fig. 18 - Forward Voltage Drop Characteristics

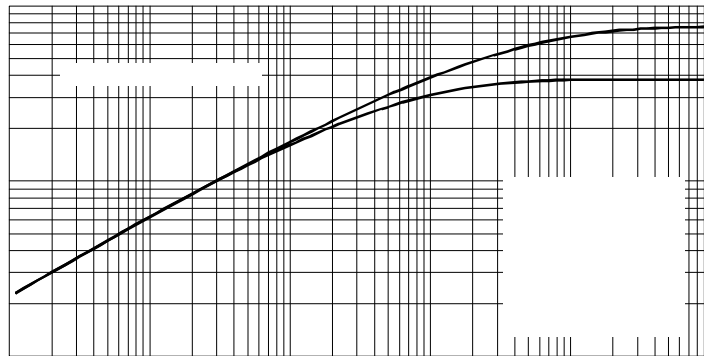


Fig. 19 - Thermal Impedance  $Z_{th-jhs}$  Characteristic

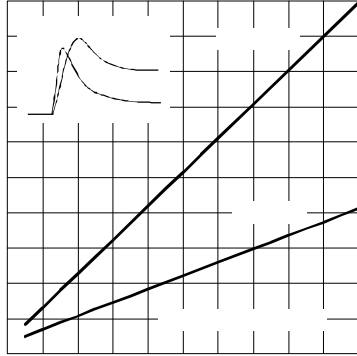


Fig. 20 - Typical Forward Recovery Characteristics

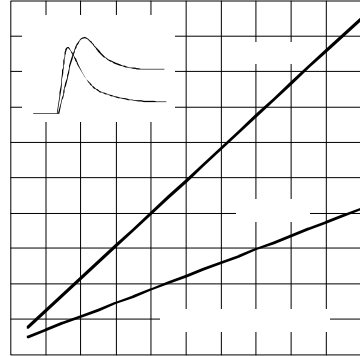


Fig. 21 - Typical Forward Recovery Characteristics

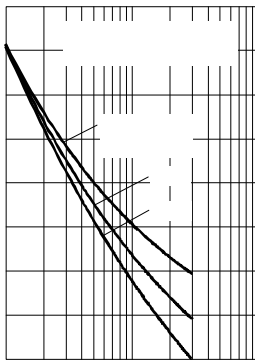


Fig. 22 - Recovery Time Characteristics

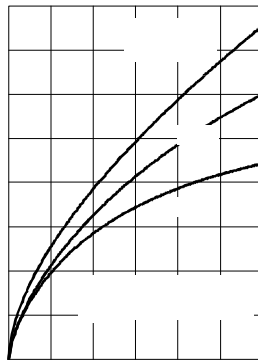


Fig. 23 - Recovery Charge Characteristics

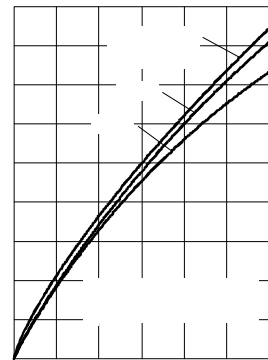


Fig. 24 - Recovery Current Characteristics

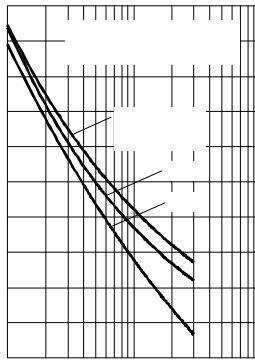


Fig. 25 - Recovery Time Characteristics

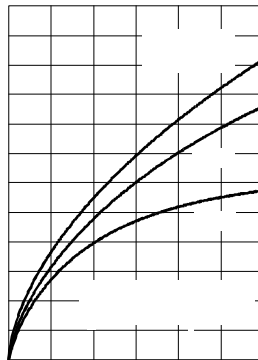


Fig. 26 - Recovery Charge Characteristics

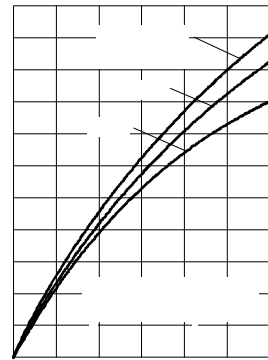


Fig. 27 - Recovery Current Characteristics

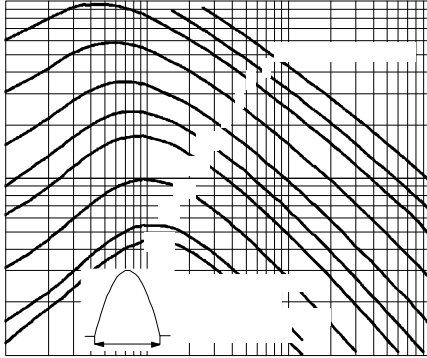


Fig. 28 - Maximum Total Energy Loss Per Pulse Characteristics

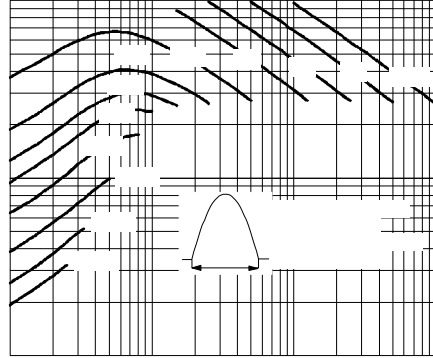


Fig. 29 - Frequency Characteristics

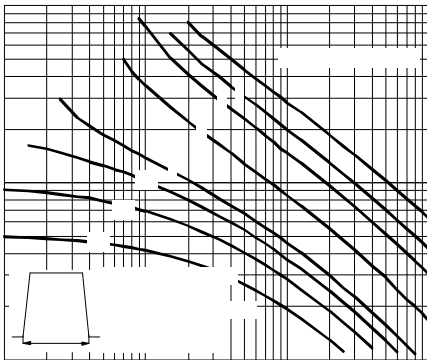


Fig. 30 - Maximum Total Energy Loss Per Pulse Characteristics

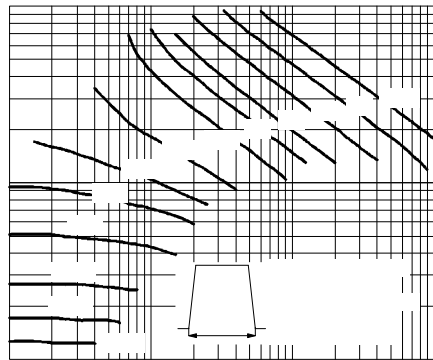


Fig. 31 - Frequency Characteristics

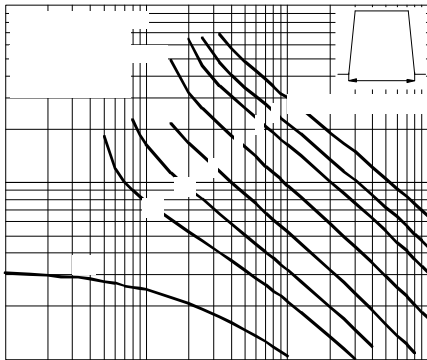


Fig. 32 - Maximum Total Energy Loss Per Pulse Characteristics

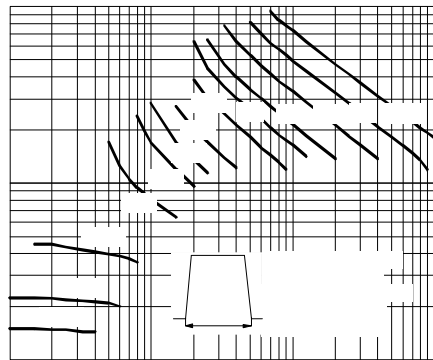


Fig. 33 - Frequency Characteristics

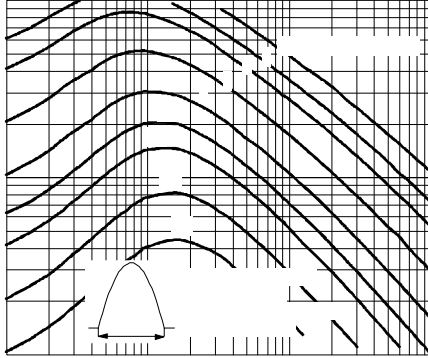


Fig. 34 - Maximum Total Energy Loss Per Pulse Characteristics

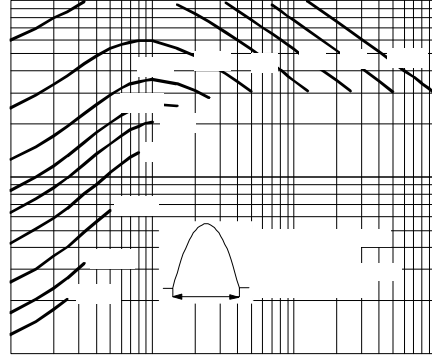


Fig. 35 - Frequency Characteristics

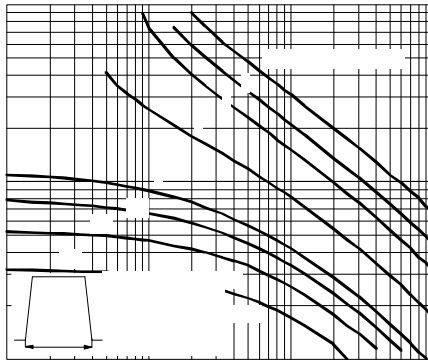


Fig. 36 - Maximum Total Energy Loss Per Pulse Characteristics

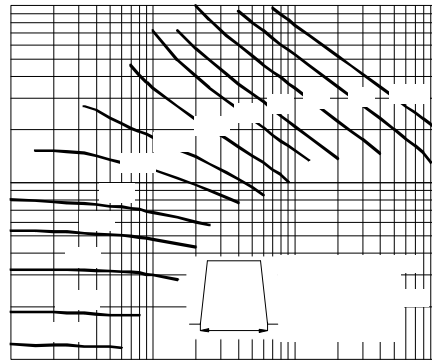


Fig. 37 - Frequency Characteristics

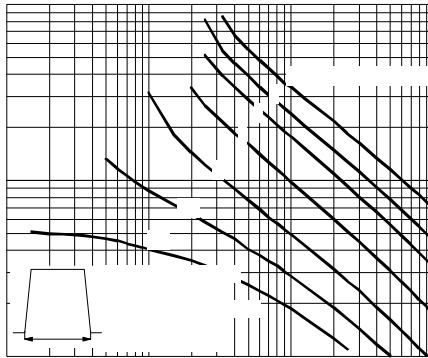


Fig. 38 - Maximum Total Energy Loss Per Pulse Characteristics

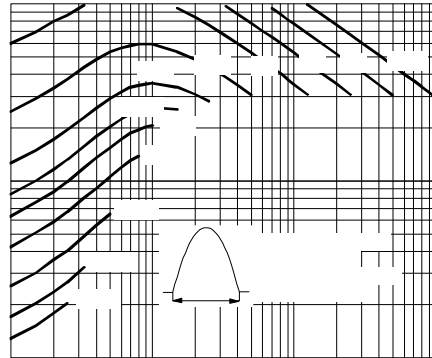


Fig. 39 - Frequency Characteristics



## Thermal and Mechanical Specifications

Parameter	SD823C..C		Units	Conditions
	S20	S30		
$T_J$ Max. junction operating temperature range	-40 to 150		°C	
$T_{stg}$ Max. storage temperature range	-40 to 150			
$R_{thJ-hs}$ Max. thermal resistance, case junction	0.076 to heatsink		K/W 0.038	DCoperation single side cooled DCoperation double side cooled
F Mounting force, $\pm 10\%$	9800 (1000)		N (Kg)	
wt Approximate weight	83		g	
Case style	B-43			See Outline Table

 $\Delta R_{thJ-hs}$  Conduction

(The following table shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.007	0.007	0.005	0.005	K/W	$T_J = T_J \text{ max.}$
120°	0.008	0.008	0.008	0.008		
90°	0.010	0.010	0.011	0.011		
60°	0.015	0.015	0.016	0.016		
30°	0.026	0.026	0.026	0.026		

## Ordering Information Table

Device Code															
<table border="1" style="display: inline-table; border-collapse: collapse;"> <tr> <td style="background-color: black; color: white; padding: 2px;">SD</td> <td style="background-color: black; color: white; padding: 2px;">82</td> <td style="background-color: black; color: white; padding: 2px;">3</td> <td style="background-color: black; color: white; padding: 2px;">C</td> <td style="background-color: black; color: white; padding: 2px;">25</td> <td style="background-color: black; color: white; padding: 2px;">S20</td> <td style="background-color: black; color: white; padding: 2px;">C</td> </tr> <tr> <td style="text-align: center;">①</td> <td style="text-align: center;">②</td> <td style="text-align: center;">③</td> <td style="text-align: center;">④</td> <td style="text-align: center;">⑤</td> <td style="text-align: center;">⑥</td> <td style="text-align: center;">⑦</td> </tr> </table>	SD	82	3	C	25	S20	C	①	②	③	④	⑤	⑥	⑦	
SD	82	3	C	25	S20	C									
①	②	③	④	⑤	⑥	⑦									
1	- Diode														
2	- Essential part number														
3	- 3 = Fast recovery														
4	- C = Ceramic Puk														
5	- Voltage code: Code x 100 = $V_{RRM}$ (See Voltage Ratings table)														
6	- $t_{rr}$ code														
7	- C = Puk Case B-43														

SD823C..C Series

Outline Table

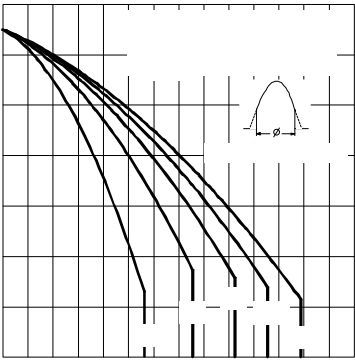
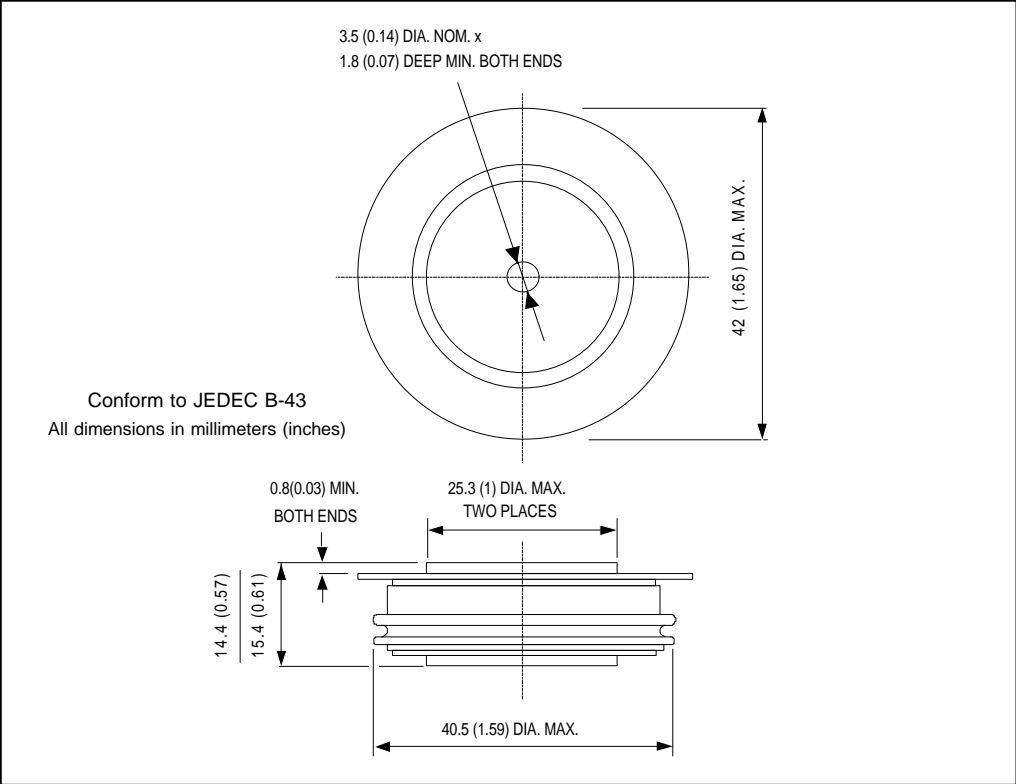


Fig. 1 - Current Ratings Characteristics

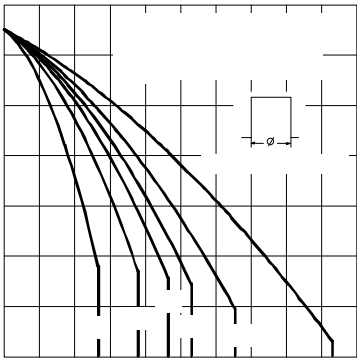


Fig. 2 - Current Ratings Characteristics